

Recent progress on APC multi-filamentary Nb_3Sn wires

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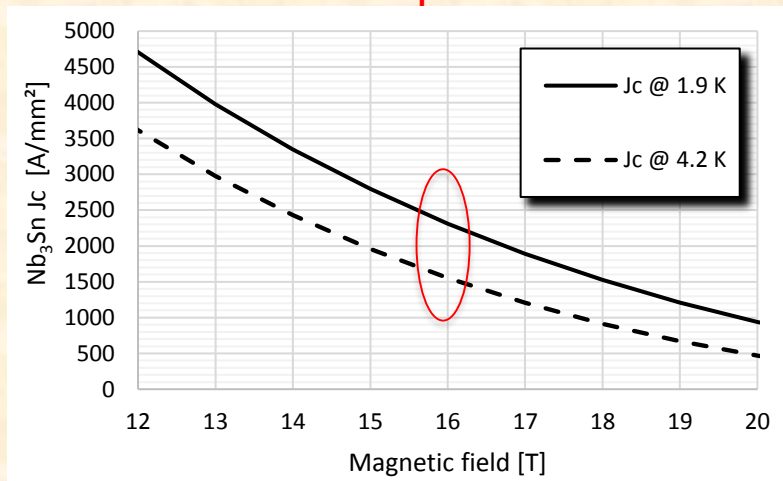
Test support from ASC/NHMFL group;

Outline of this Talk

- Motivation of this Project
- Brief History Review of APC wire
- Report the fabrication and properties of the recent Ta doped APC wires
- Further Optimization
- Fabrication of APC wires and their Price Projection
- Sumary

Motivation of this Project

FCC conductor specification:



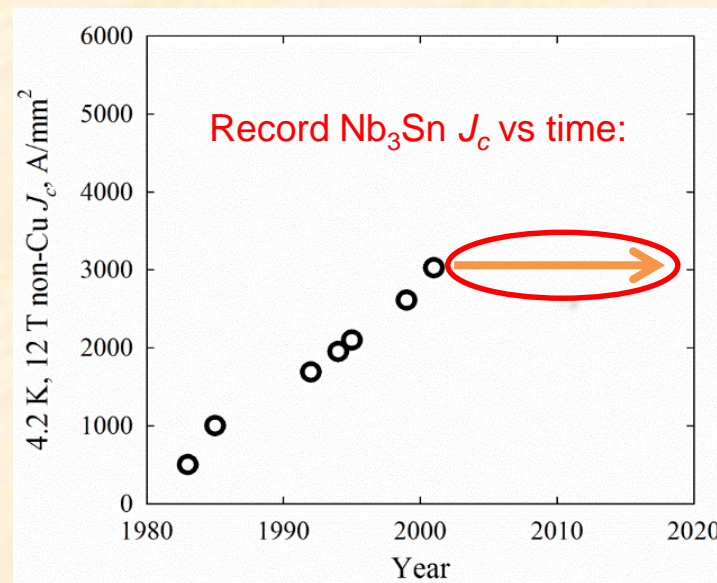
EuroCirCol-P1-WP5 report, CERN, 2016.

Need nearly 40% improvement of J_c .

Create Artificial Pinning Center (APC)

There is still a lot of room for improving pinning:

1. $J_c \propto 1/\text{grain size}$;
2. Small pinning center spacing \rightarrow shift in F_p - B peak to improve B_{c2} .
3. Doping



J. Parrell et al., *IEEE Trans. Appl. Supercond.* 13 3470-3, 2003:

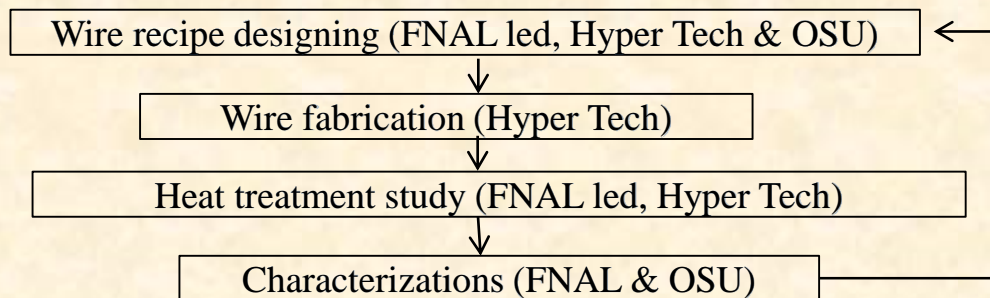
The highest J_c has plateaued for nearly two decades, in spite of efforts to:

- adjust Nb/Sn/Cu ratio
- adjust LAR (0.13, 0.2, 0.23, hybrid, etc.)
- adjust doping (7.5%Ta, 1.5%Ti, 2.0%Ti, 3.2%Ti, 7.5%Ta+0.9%Ti, etc.)
- adjust heat treatment (FSU)
- adjust barrier composition (pure Nb, Nb-7.5%Ta)

Brief History Review of Hyper Tech APC wire

A lot of efforts on APC Nb₃Sn since the 1980s: only became possible recently

- 2014: started on making APC Nb₃Sn monofilaments by internal oxidation in Hyper Tech through collaboration with OSU, and got great layer J_c in monofilaments.
X. Xu, M. Sumption, X. Peng, E. Collings, Appl. Phys. Lett. 104, 082602 (2014)."
- Late 2015-2016: made binary PIT multi-filament wires, with high layer J_c but low B_{c2} .
- From 2017: Develop Ta-doped Ternary APC PIT multi-filament wires through collaboration with Fermilab and OSU. Great progress has been made since then. This is a joint effort.



- First Ta-doped wire tested at NHMFL in 09/2018: proved high B_{c2} , J_c over HL-LHC spec.
- Recent wires tested at NHMFL in Jan 2019, J_c over FCC spec.
- Latest wire tested by FSU group in NHMFL in April 2019, confirmed the J_c over FCC spec at high field.
- Also inspired other groups to pursue the APC approach:
 - ASC/NHMFL: explore Hf doping without oxygen.
 - U. Geneva & CERN: work on monofilaments, similar to what we started with.

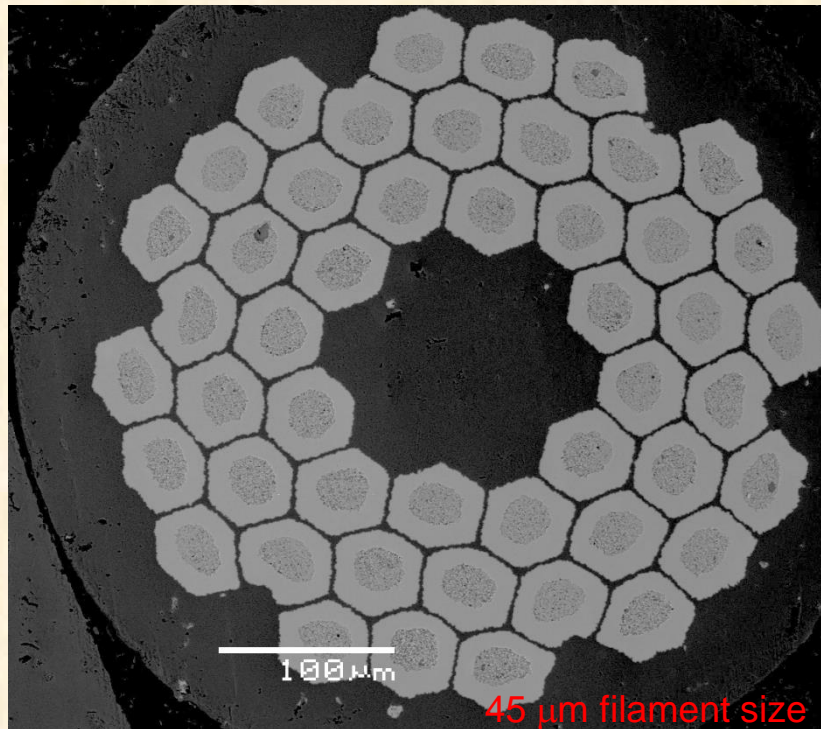
Fabrication and Properties of the Recent Ta Doped APC Wires

U.S. Patent No. 9,916,919

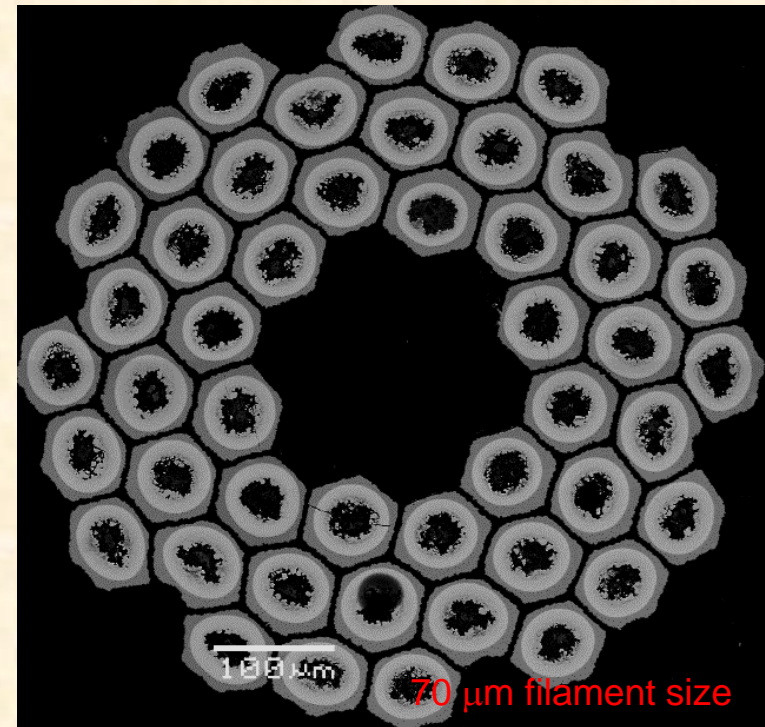
Ta-doped APC wires have Good Drawability

About 25 wires of 48/61 design has been made using Nb-Ta-Zr tubes, none had any breakage during wire drawing (100-200 meters of wire at 0.5mm-0.84 mm per billet).

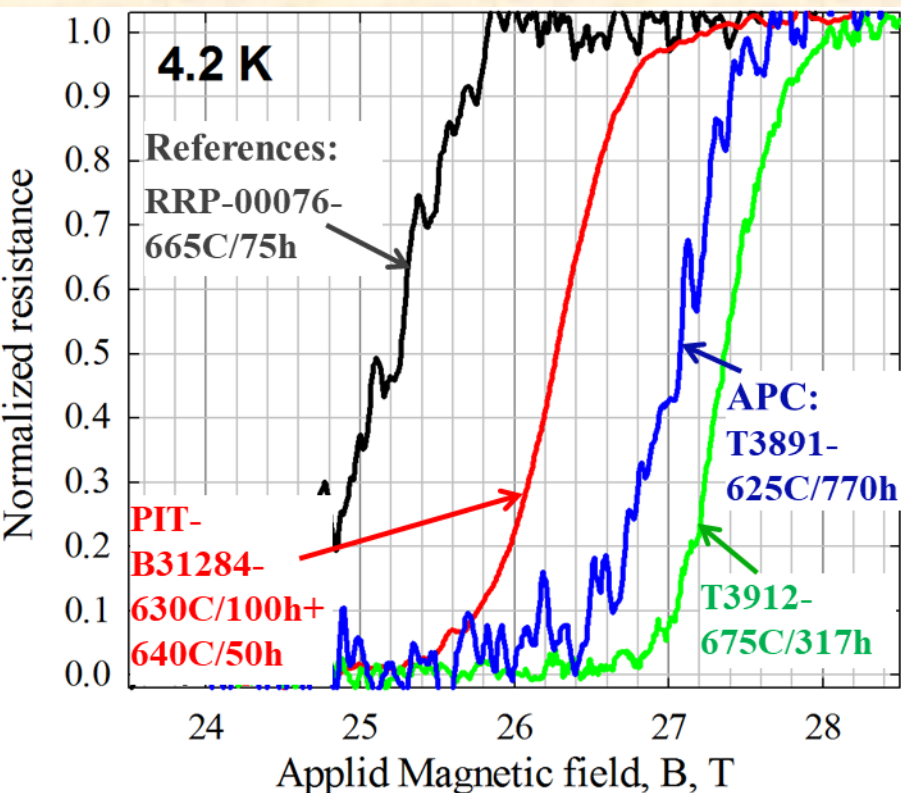
T3912-0.5mm-unreacted



T3912-0.71mm-700C/71h



Ta-doped APC wires have higher B_{c2} than present wires



Transport R - B tests, done by X. Xu and M. Sumption in NHMFL, a 31T magnet. **Many thanks to Jan Jaroszynski for the help.**

Wire	D, mm	Design	Composition
RRP-00076	0.85	108/127	1.5at.% Ti doped
PIT-B31284	0.78	192/217	7.5 wt.% Ta
APC-T3891	0.84	48/61	7.5% Ta, 1%Zr + O
APC-T3912	0.84	48/61	7.5% Ta, 1%Zr + O

Data provided by X. Xu, Fermilab

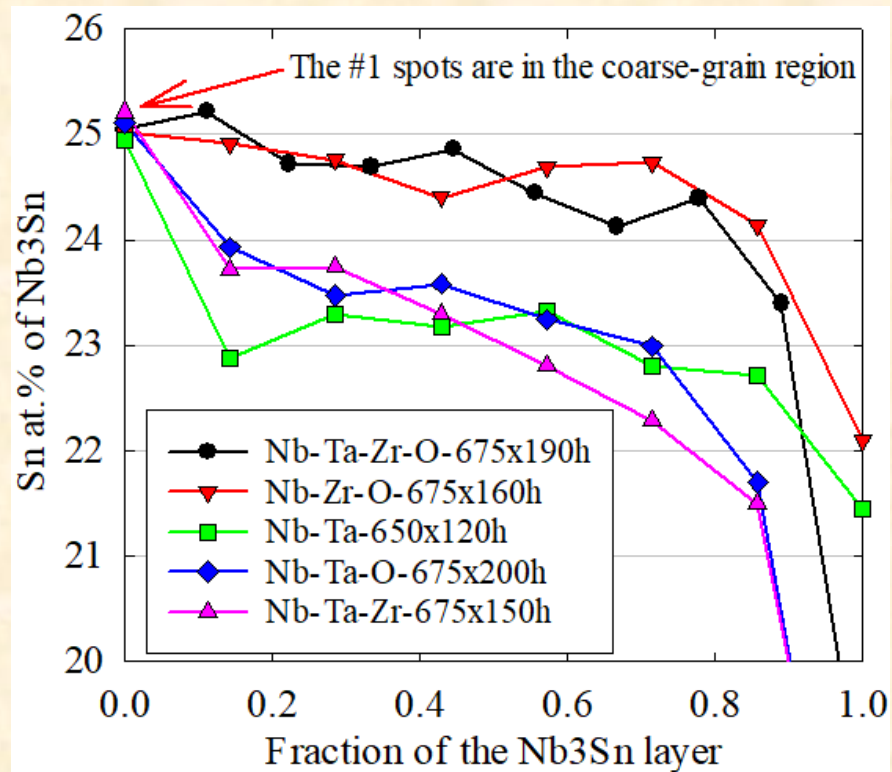
- Ternary APC wire T3891: tests in 09/2018 showed B_{irr} (B_{c2}) of 26-27 T at 4.2K, higher than present-day wires.
- Further confirmed by the tests of new wires T3912 in 01/2019.

Courtesy X. Xu et al. 1. <https://arxiv.org/abs/1903.08121>
2. *Supercond. Sci. Technol.* **32** 02LT01

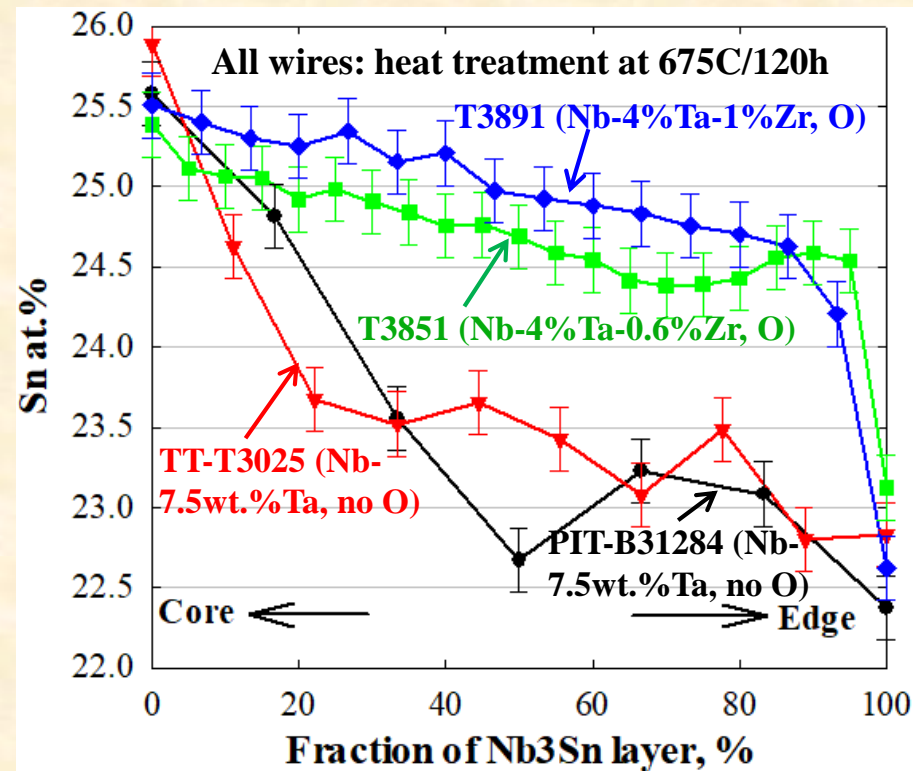
A unique feature of APC Nb₃Sn: high Sn content in A15

What accounts for the high B_{irr} (B_{c2}) in the APC wires?
better stoichiometry \rightarrow higher B_{c2} (B_{irr})

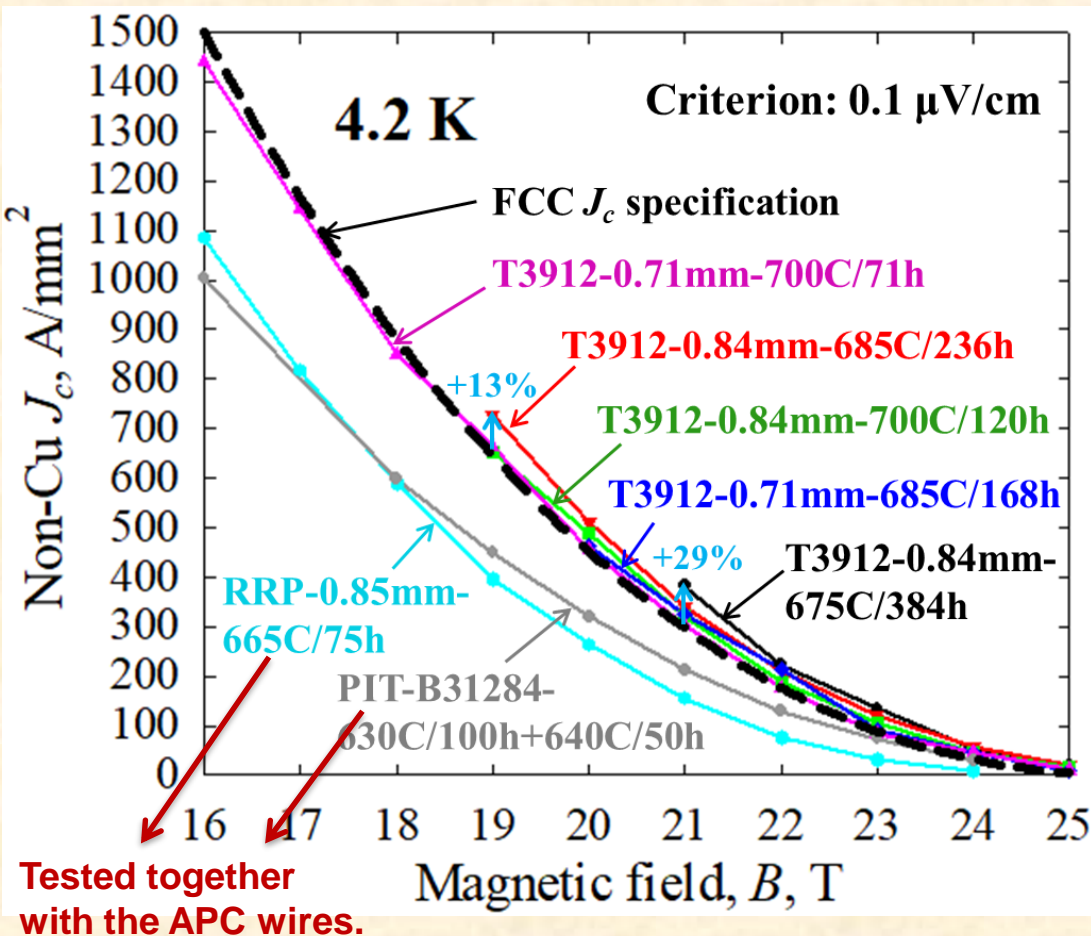
1st measurement by X. Xu at FNAL



Confirmation measurements by I. Pong
at LBNL: EDS line scans



Ta-doped APC wires have non-Cu J_c above FCC SPEC



Wire	Design	Composition
RRP-00076	108/127	1.5at.% Ti doped
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Data provided by X. Xu, Fermilab

Observations

1. Wires of 0.71 and 0.84mm have similar J_c s (D_s : 70 vs 83 μm).
2. Lower HT temperature leads to higher J_c (700 \rightarrow 685 \rightarrow 675 C).
3. Nb₃Sn record J_c began to grow again after a 2-decade plateau.
4. Need HT optimization for RRR.
5. Need to reduce the filament size by making higher count restack.

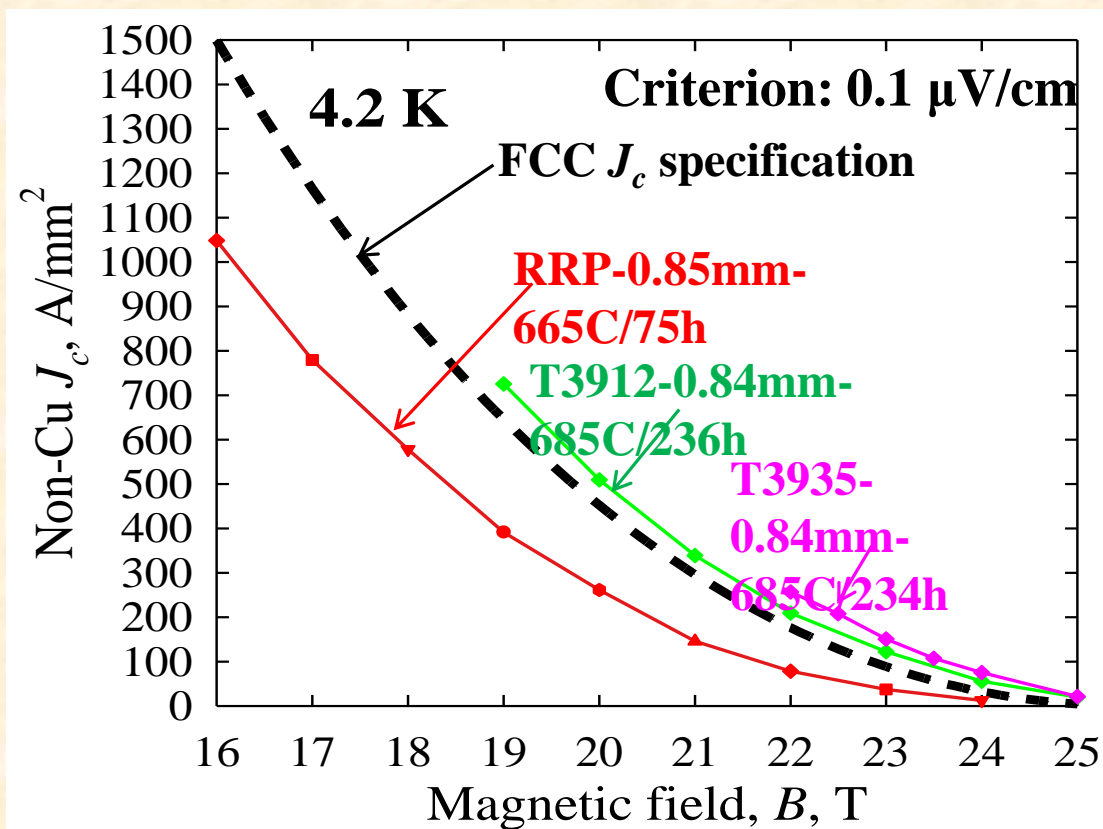
Tested by X. Xu and M. Sumption in a 31 T magnet at the NHMFL in January 2019.

Many thanks to ASC/FSU for the I_c rig, PS, DAQ, program, etc., for the I_c tests in NHMFL.

Latest Ta-doped APC wire has non-Cu J_c above FCC Spec

A new wire (T3935) was made recently. Tested independently by S. Balachandran from ASC/NHMFL/FSU in April 2019.

Wire	Wire description	Tested
RRP	Standard RRP for HL-LHC	by FSU in Apr.
T3912	1at.%Zr + oxygen. But O is insufficient for some filaments.	by FNAL and OSU in Jan.
T3935	1at.%Zr + oxygen. Oxygen is sufficient for all filaments.	by FSU in Apr.



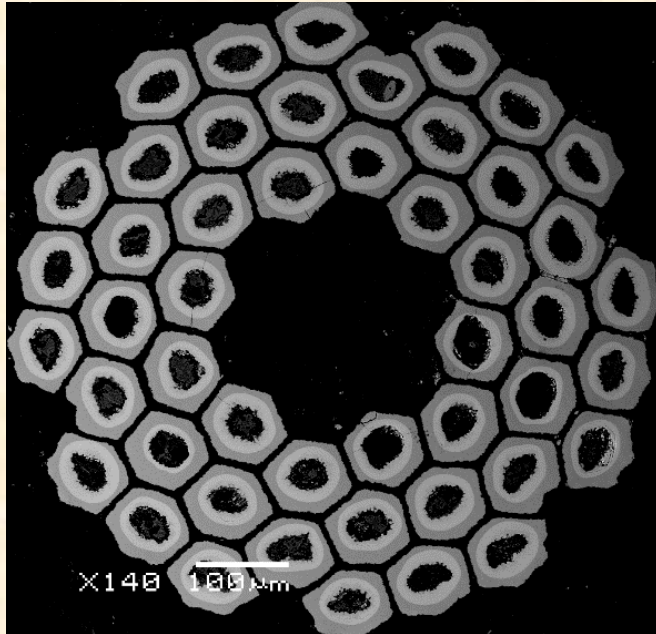
Observations

Data provided by X. Xu, Fermilab

- 1.The recent T3935 has 15% higher J_c than previous T3912, perhaps due to more oxygen.
- 2.The J_c above FCC spec is verified by independent tests by FSU.
- 3.Need to make filaments smaller to make the wire stable in the lower field.

Why high non-Cu J_c in Ta doped APC wires

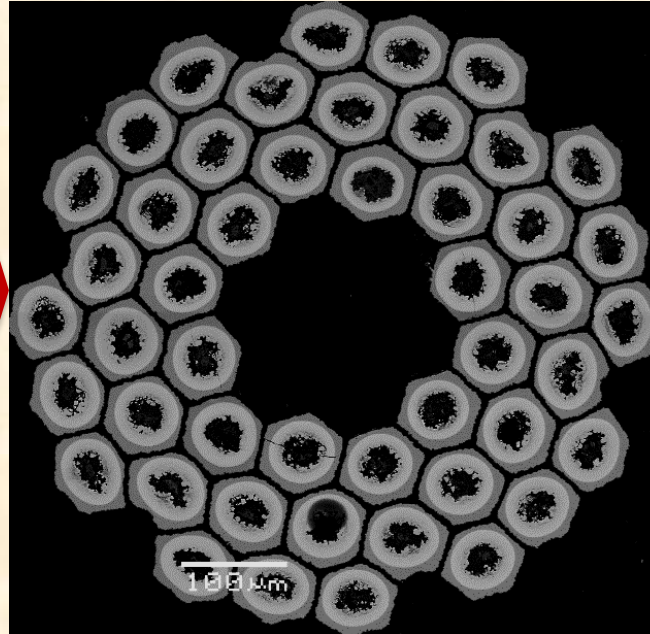
Sept. 2018: T3882-0.84mm-675C/330h



1040 A/mm² at 16T

FG Nb ₃ Sn %	Residual Nb%
22%	45%

Jan. 2019: T3912-0.71mm-700C/71h



1500 A/mm² at 16T

FG Nb ₃ Sn %	Residual Nb%
32%	33%

Development is still ongoing: further optimization of recipe.

The goal: similar to standard PIT wires.

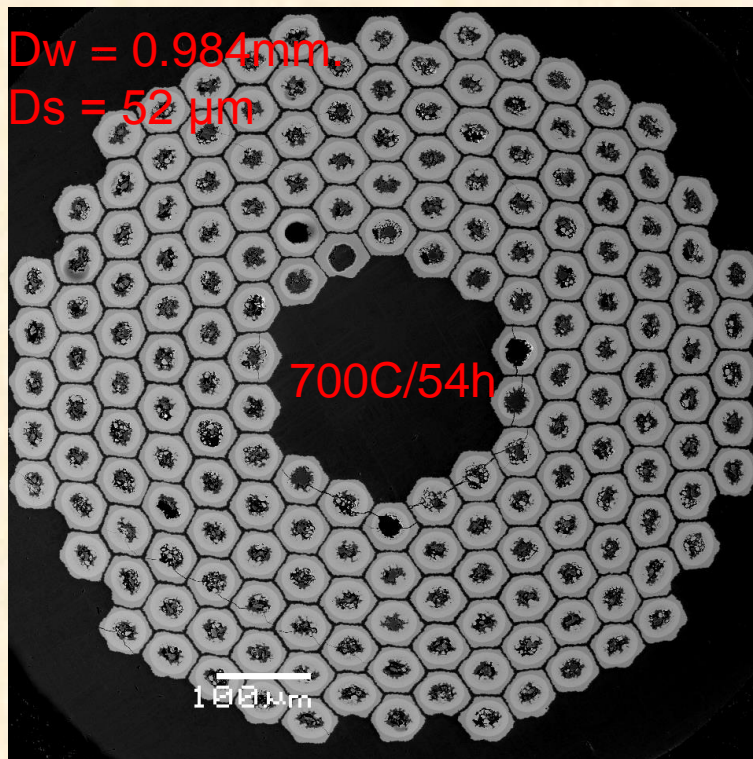
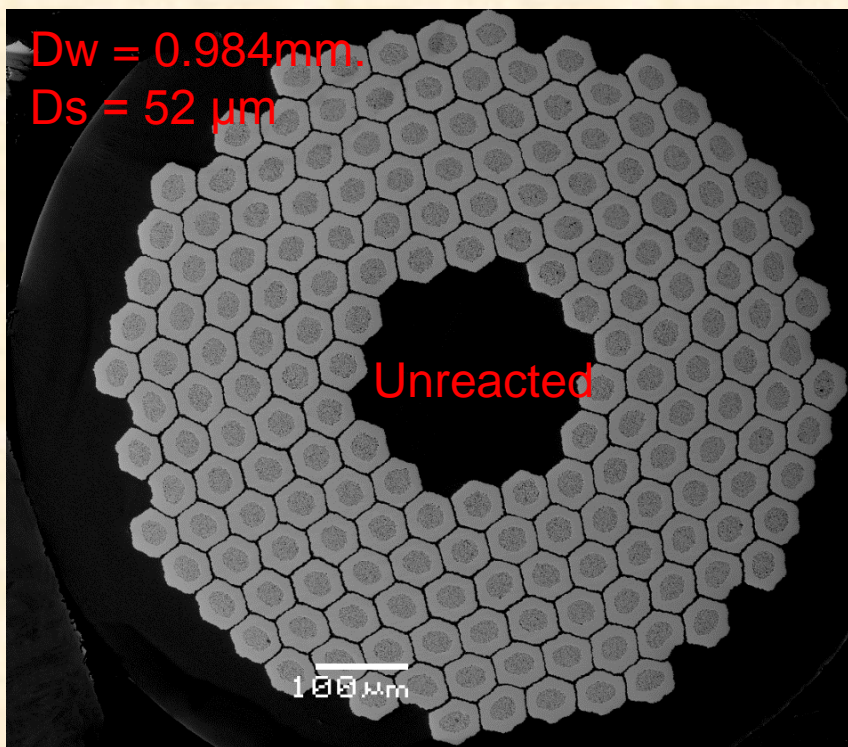
FG Nb ₃ Sn %	Residual Nb%
40%	25%

Observations

- Compared with the J_c obtained in T3882, the J_c s of T3912 are ~50% higher.
- This increase was due to higher A15 fraction, driven by improvement of wire recipe.
- Nb₃Sn layer J_c stayed similar, around 4700 A/mm² at 16T.
- T3912 still has too high Nb/Sn ratio and there is not enough Sn for a full reaction. It is improved in T3935, but the characterization is still going on.
- Other factors for J_c improvement: Filament uniformity; Heat treatment optimization (lower HT temperature).

Fabrication of 217-restack APC wires turned out good

217-pattern (180 filaments +19 Cu in the middle) restack wire was made and drawn down to 1.2 and 1.0 mm diameters with filament size of 63 μm and 52 μm respectively.



- ❑ No breakage, about 100-200 meter of different diameter wires per billet.
- ❑ J_c has not been measured yet, but SEM images shows promising.
- ❑ T3912 recipe was used here and will further be optimized based on the smaller filaments.

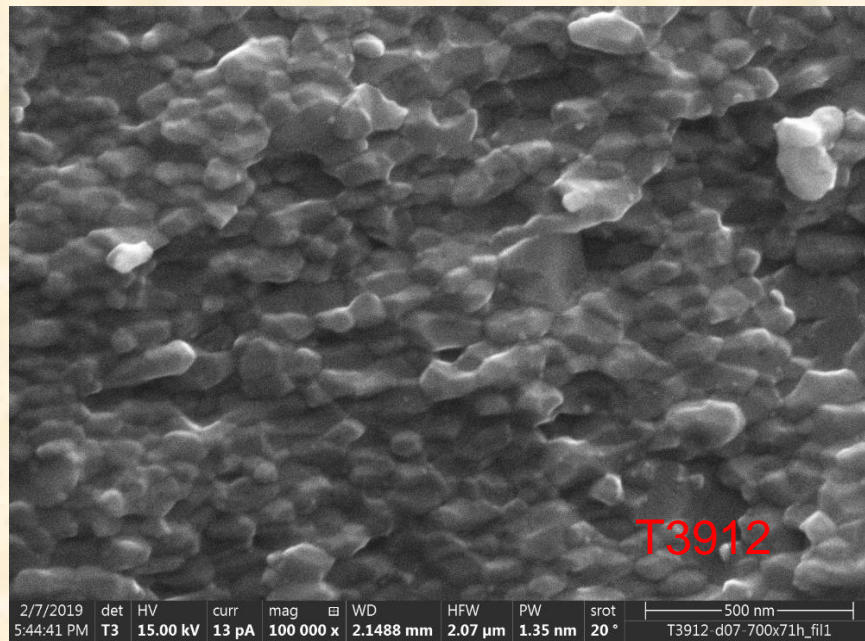
Work related to Nb-Ta-Hf with Internal Oxidation

FSU group: Ta, Hf doped without internal oxidation.

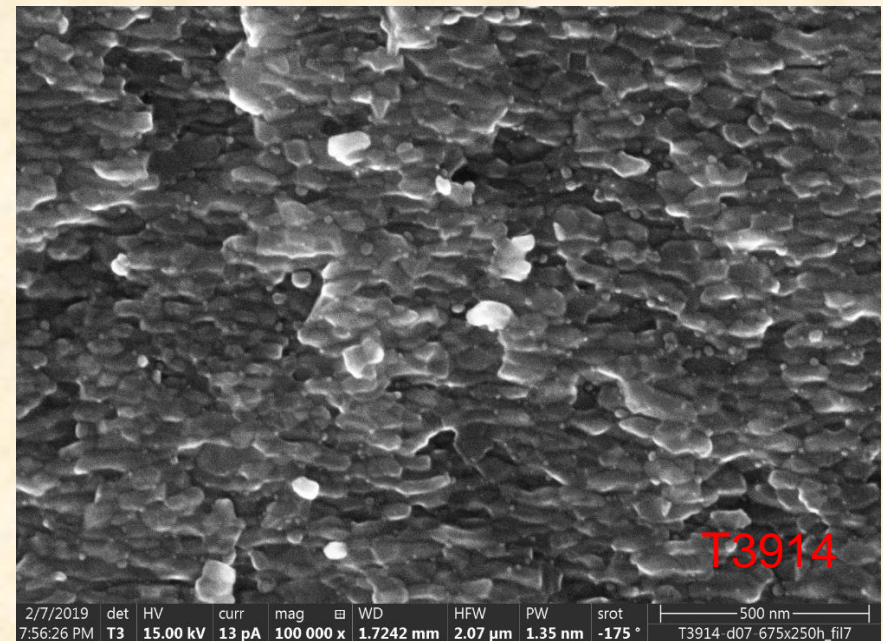
See Dr. S. Balachandran's talk next

Hf is a Hc2 enhancer as well as a prospective oxidizer

Hyper Tech selected the 1 at% Hf, and made the Nb-Ta-Hf alloy into tubes and made a wire T3914 using internal oxidation.



Champion wire with Nb-Ta-1Zr tube



Wire with Nb-Ta-2Hf tube

Ta-Hf additions also look promising and deserve more investigation with and without oxidation.

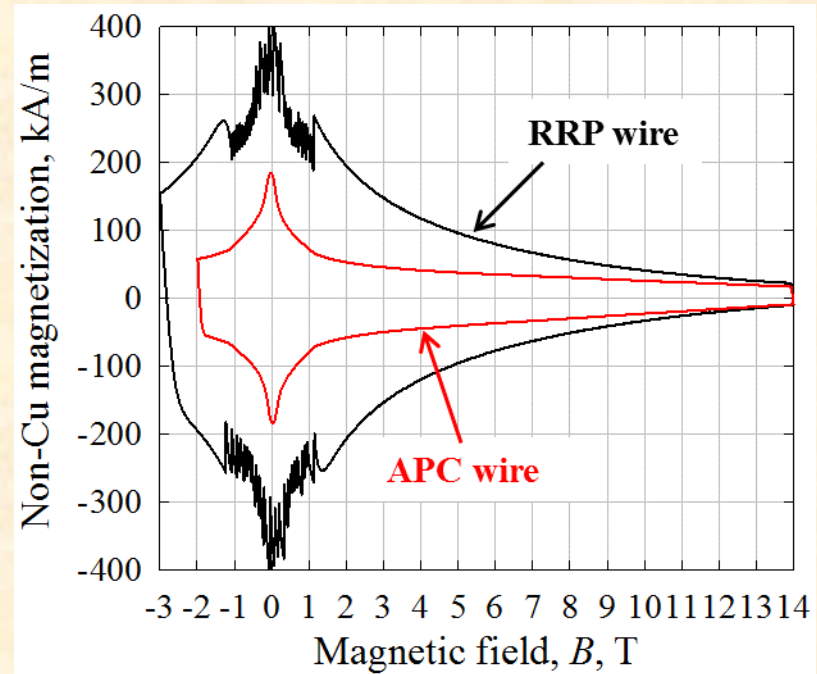
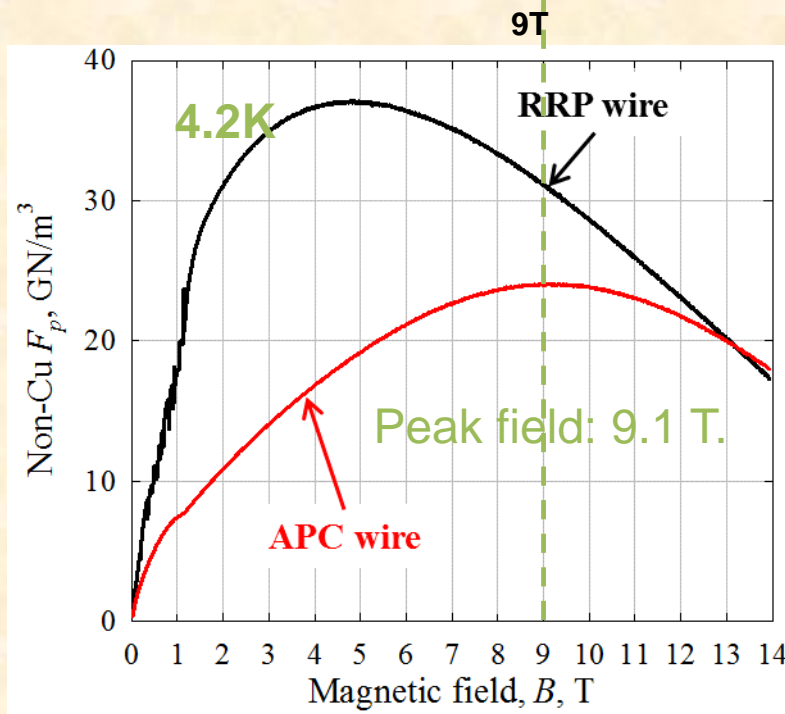
New SBIR Phase I Fund from DOE: DE-SC0019816

Extra benefit of internally oxidized APC wires – flatter J_c - B curve

Apart from the much higher J_c , the internally oxidized APC wires have an extra benefit: ZrO_2 or HfO_2 particles serve as point pinning centers, causing F_p - B curve shift to higher fields.

An example: T3914 (Hf + O), reacted at 625C.

Data provided by X. Xu, Fermilab



The F_p - B curve of the standard RRP wire peaks at ~ 4.9 T, while that of the T3914 wire peaks at ~ 9.1 T.

As a result, the J_c - B curve of the APC wire is much flatter, causing much lower magnetization at 1-2 T. This reduces flux jumps, field errors, and a.c. losses.

Note: this APC layer has thin Nb_3Sn layer due to insufficient reaction, causing low non-Cu J_c .

Further Optimization Next

These results of the prototype wires demonstrate improved J_c , but they are still far away from maturity. Much more work is required.

(1) Further optimization in recipe → $\left\{ \begin{array}{l} \text{Higher Nb}_3\text{Sn \%} \rightarrow \text{higher } J_c \\ \text{Higher wire quality} \rightarrow \text{higher RRR} \end{array} \right.$

(2) Further optimization in HT → $\left\{ \begin{array}{l} \text{Lower HT temperature} \rightarrow \text{higher } J_c \\ \text{Optimized reaction time} \rightarrow \text{higher RRR} \end{array} \right.$

(3) 217-restack wires → smaller D_s → better conductor stability.

(4) Other better designs, e.g., bundle-barrier (or other barrier) → high RRR

(5) Better bonding, larger billet (2"), round filament → cabling

(6) Other necessary tests, e.g., uniaxial tensile, transverse pressure, etc.

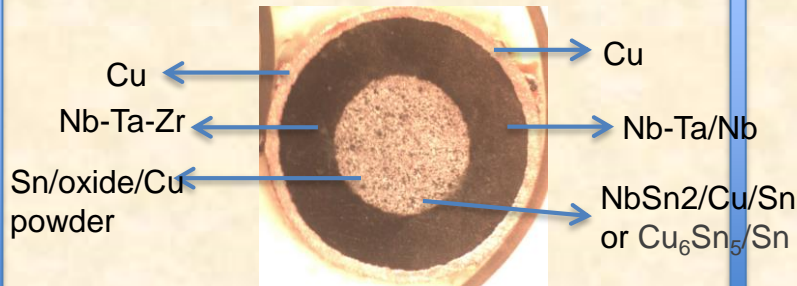
(7) Wire quality control: eddy current device to check the wire quality along the length..

Fabrication of APC wires and their Price Projection

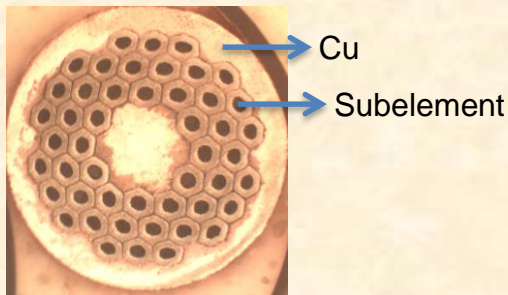
APC PIT wire

Purchase Materials (Nb-Ta-Zr tube, Cu tube, Sn/oxide/Cu powder)

Make Subelement (fill the tube and then draw)



Make restack (Cut Subelement, restack in multi, and draw it down)



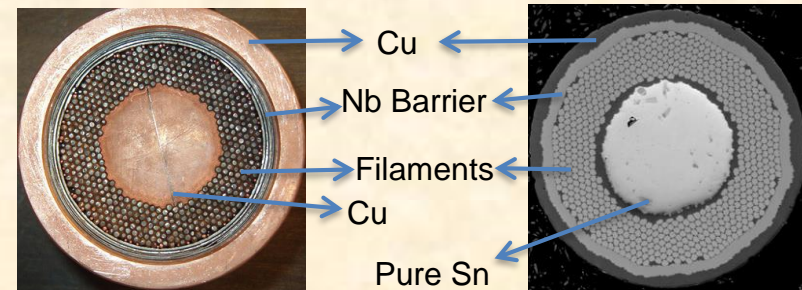
Regular PIT wire

Purchase Materials (Nb-Ta tube, Cu tube, Jet milled and classified NbSn₂ or Cu₆Sn₅ powder)

Make Subelement (fill the tube and then draw)

Cu
Nb-Ta/Nb
NbSn₂/Cu/Sn
or Cu₆Sn₅/Sn

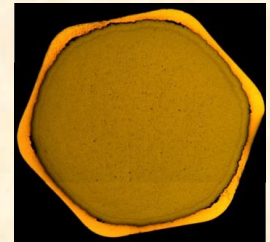
Make Subelement (Cut the filaments and restack a few hundreds filaments around Cu filaments in a Cu can, EB weld the end, then extrude the billet down, gundrill the hole in the middle, insert Sn, then draw it to the size for restack)



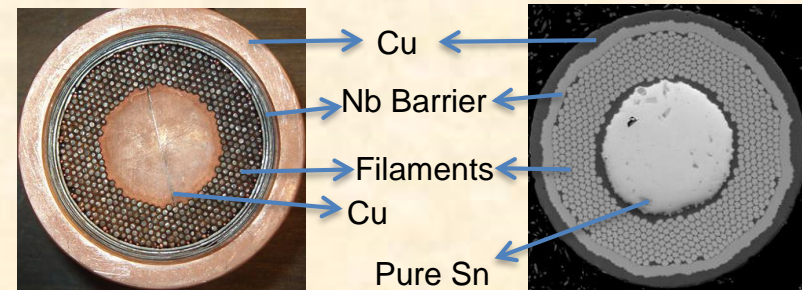
RIT wire (RRP)

Purchase Materials (Nb rod or ingot, Cu tube, Sn rod)

Make filament (stack the Nb rod in Cu tube and draw it down; or extrude and shape it to make better shapes)



Make Subelement (Cut the filaments and restack a few hundreds filaments around Cu filaments in a Cu can, EB weld the end, then extrude the billet down, gundrill the hole in the middle, insert Sn, then draw it to the size for restack)



Fabrication of APC wires and their Price Projection

- Comparing to regular PIT process, APC PIT has similar procedure, but use much cheaper commercially available powder instead of costly intermetallic NbSn₂ or Cu₆Sn₅ plus jet mill and classification.
- Comparing to RIT (RRP) process, APC PIT has much simpler process and avoid the cost of the various processes and also reduces the labor cost although the Nb alloy tube material used is a little expensive than the rod material, it will reduce if high quantities are ordered at one time.
- Rough estimation shows the APC wire price is comparable or even less than RIT wires (RRP).
- Very fast turnaround, considerably less in process time and inventory.

Summary

1. Development of Ta doped ternary APC-PIT multi wires started in 2017 and great progress has been made.
2. Tests up to 31 T at 4.2 K show that B_{irr} is 26-27 T, B_{c2} is 27-28 T, ~ 1 -2 T higher than present wires.
3. R&D in the past two years has led to significant improvement of wire recipe and wire quality. The non-Cu J_c s have broken the Nb₃Sn $J_{c,non-Cu}$ record that stood for nearly two decades and have achieved the $J_{c,non-Cu}$ specification required by the Future Circular Collider (FCC),.
4. The Nb₃Sn layer J_c at 16 T is 4700 A/mm² which is ~ 2.5 times of the present wires despite grain size not fully refined.
5. 217-restack wire has been made and draw down to about 1 mm with filament size of 52 μ m.
6. While these wire properties have been obtained with Ta-Zr additions, Ta-Hf additions also look promising and deserve more investigation with and without oxidation.
7. The improvement is still ongoing. The following levels are expected.
 - 1) By improving conductor recipe and quality and heat treatment, the fine-grain Nb₃Sn fraction can be increased to $\sim 40\%$, as in standard tube type and PIT wires.
 - 2) By optimizing O content and heat treatment, the grain size can be reduced to 50-65 nm or less, which leads to a Nb₃Sn layer J_c of 5000-6000 A/mm² for 4.2 K, 16 T.

If so, this means the 4.2 K, 16 T non-Cu J_c can reach 2000-2400 A/mm². This will surpass the FCC spec and also provide $>30\%$ margin.

Above 16 T, the APC conductors should give extra J_c gain due to higher B_{irr} and shift in F_p -B curve peak to higher fields.

Thank you for your attention!